Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

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COMPLEMENTARY OUTPUT HALL EFFECT LATCH AH276

General Description

The AH276 is an integrated Hall sensor with output driver designed for electronic commutation of brushless DC motor applications. The device includes an on-chip Hall sensor for magnetic sensing, an amplifier that amplifies the Hall voltage, a Schmitt trigger to provide switching hysteresis for noise rejection, a temperature compensation circuit to compensate the temperature drift of Hall sensitivity and two complementary open-collector drivers for sinking large load current. It also includes an internal band-gap regulator which is used to provide bias voltage for internal circuits.

Placing the device in a variable magnetic field, if the magnetic flux density is larger than threshold B_{OP}, the pin DO will be turned low (on) and pin DOB will be turned high (off). This output state is held until the magnetic flux density reverses and falls below B_{RP}, then causes DO to be turned high (off) and DOB turned low (on).

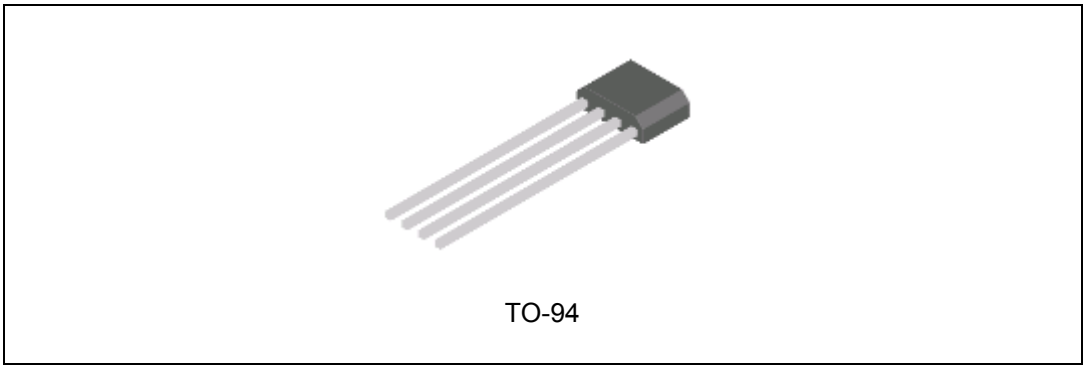
AH276 is available in TO-94 (SIP-4L) package.

Features

- On-Chip Hall Sensor
- 3.5V to 16V Supply Voltage
- 350mA (avg) Output Sink Current
- Reversed Supply Voltage Protection
- Build in Over Temperature Protection Function
- -20°C to 85°C Operating Temperature
- Low Profile TO-94 (SIP-4L) Package
- ESD Rating: 300V (Machine Model)

Applications

- Dual-Coil Brushless DC Motor
- Dual-Coil Brushless DC Fan
- Revolution Counting
- Speed Measurement



TO-94

Figure 1. Package Type of AH276

Pin Configuration

Z4 Package
(TO-94)

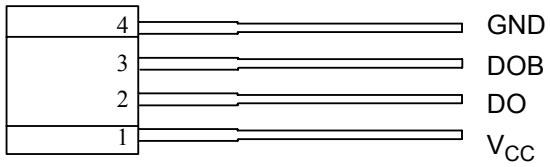


Figure 2. Pin Configuration of AH276 (Front View)

Pin Description

Pin Number	Pin Name	Function
1	V_{CC}	Supply voltage
2	DO	Output 1
3	DOB	Output 2
4	GND	Ground

Functional Block Diagram

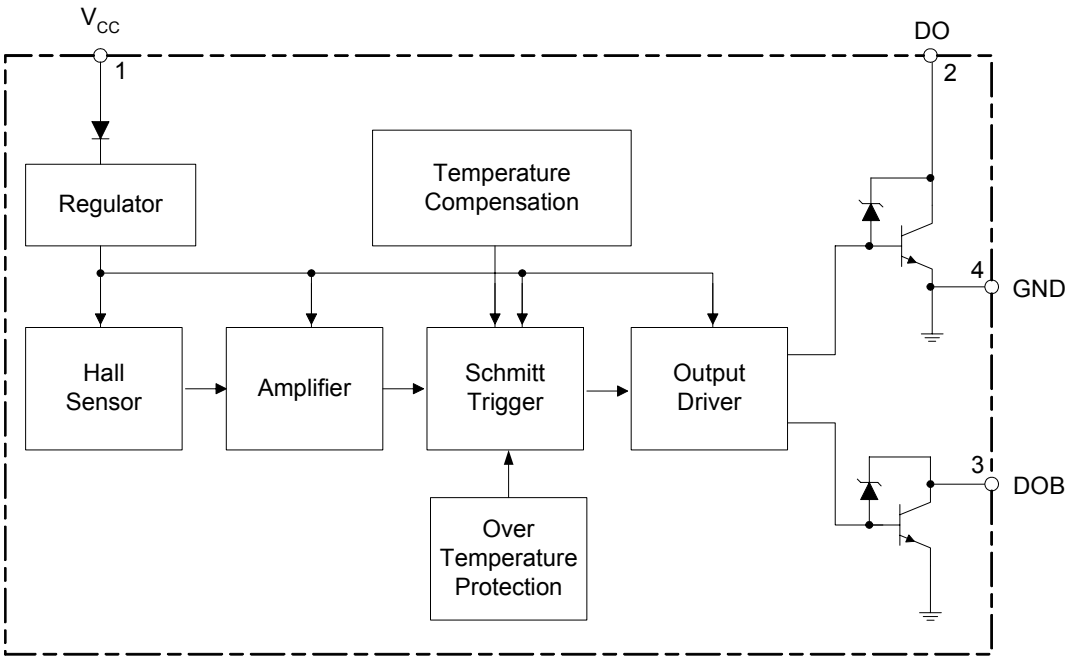
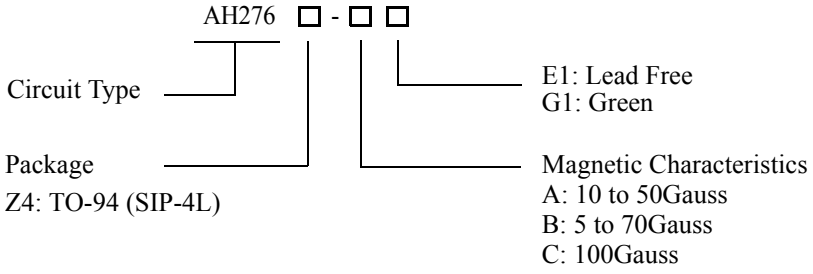


Figure 3. Functional Block Diagram of AH276

Ordering Information



Package	Temperature Range	Part Number		Marking ID		Packing Type
		Lead Free	Green	Lead Free	Green	
TO-94	-20 to 85 °C	AH276Z4-AE1	AH276Z4-AG1	AH276Z4-E1	AH276Z4-G1	Bulk
		AH276Z4-BE1	AH276Z4-BG1	AH276Z4-E1	AH276Z4-G1	Bulk
		AH276Z4-CE1	AH276Z4-CG1	AH276Z4-E1	AH276Z4-G1	Bulk

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green package.

Absolute Maximum Ratings (Note 1)

(T_A=25°C)

Parameter		Symbol	Value	Unit
Supply Voltage		V_{CC}	20	V
Reverse Protection Voltage		V_{RCC}	-20	V
Magnetic Flux Density		B	Unlimited	Gauss
Output Current	Continuous	I_O	350	mA
	Hold		550	mA
	Peak (start up)		750	mA
Power Dissipation		P_D	550	mW
Thermal Resistance	Die to atmosphere	θJA	227	°C/W
	Die to package case	θJC	49	°C/W
Storage Temperature		T_{STG}	-50 to 150	°C
ESD (Machine Model)			300	V
ESD (Human Body Model)			2500	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. "Absolute Maximum Ratings" for extended period may affect device reliability.

Recommended Operating Conditions

(T_A=25°C)

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V_{CC}	3.5	16	V
Ambient Temperature	T_A	-20	85	°C

Electrical Characteristics

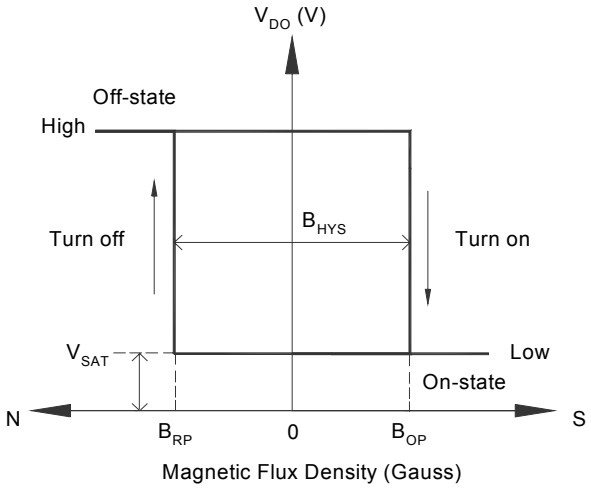
(T_A=25°C, V_{CC}=14V, unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output Saturation Voltage	V_{SAT}	V_{CC}=3.5V, I_O=100mA		0.3		V
		I_O=350mA		0.35	0.6	V
Output Leakage Current	I_{OL}	V_{CE}=16V		0.1	10	μA
Supply Current	I_{CC}	V_{CC}=16V, Output Open		12	16	mA
Output Rise Time	tr	R_L=820Ω, C_L=20pF		3.0	10	μs
Output Fall Time	tf	R_L=820Ω, C_L=20pF		0.3	1.5	μs
Switch Time Differential	Δt	R_L=820Ω, C_L=20pF		3.0	10	μs
Output Zener Breakdown Voltage	V_Z			55		V
Thermal Protection Temperature	TSD			178		°C
Thermal Protection Hysteresis	ΔTSD			40		°C

Magnetic Characteristics

(T_A=25°C)

Parameter	Symbol	Grade	Min	Typ	Max	Unit
Operating Point	B_{OP}	A	10		50	Gauss
		B	5		70	Gauss
		C			100	Gauss
Releasing Point	B_{RP}	A	-50		-10	Gauss
		B	-70		-5	Gauss
		C	-100			Gauss
Hysteresis	B_{HYS}			75		Gauss



Magnetic Characteristics (Continued)

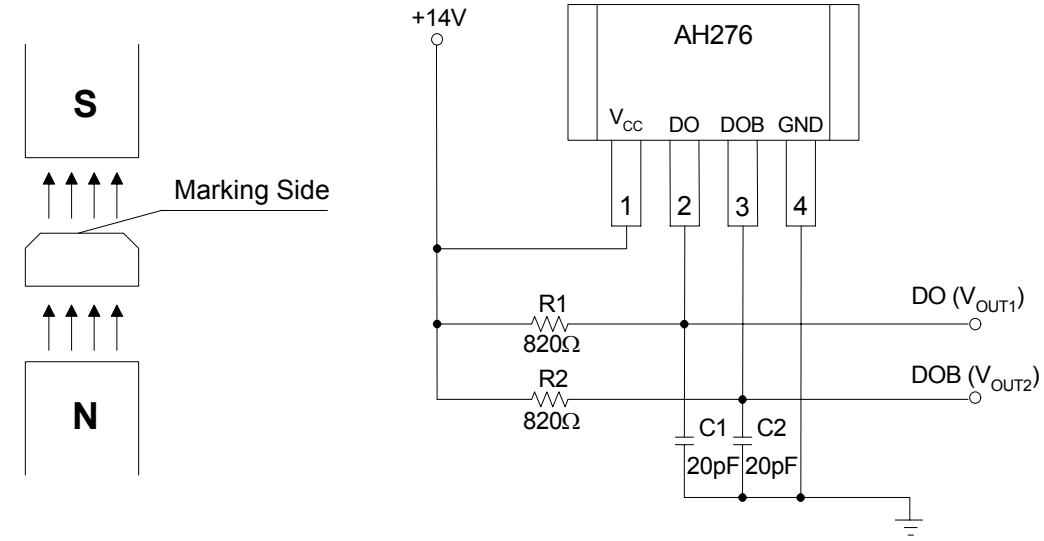


Figure 4. Basic Test Circuit

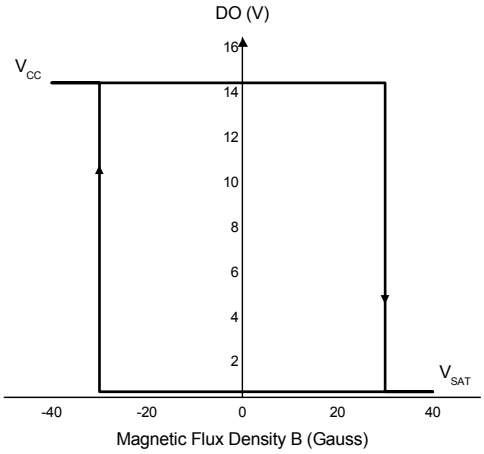


Figure 5. V_{DO} vs. Magnetic Flux Density

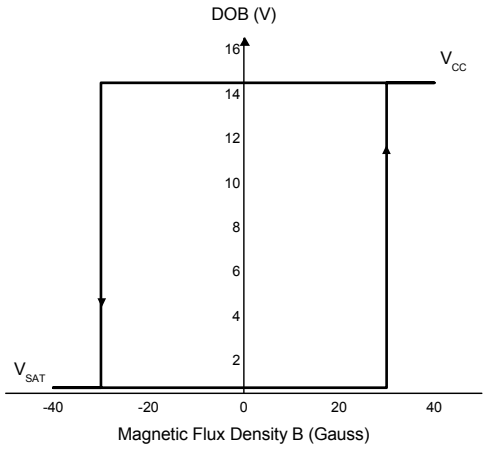


Figure 6. V_{DOB} vs. Magnetic Flux Density

Typical Performance Characteristics

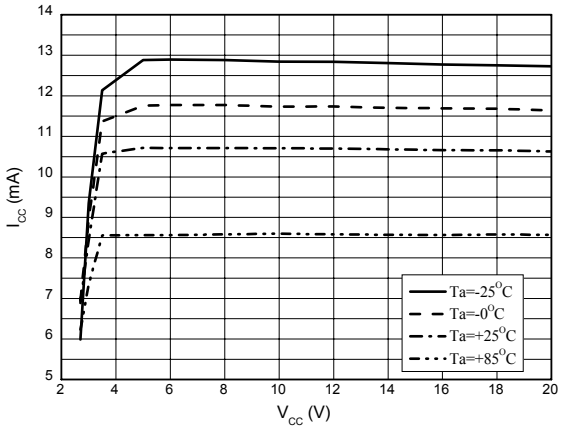


Figure 7. I_{CC} vs. V_{CC}

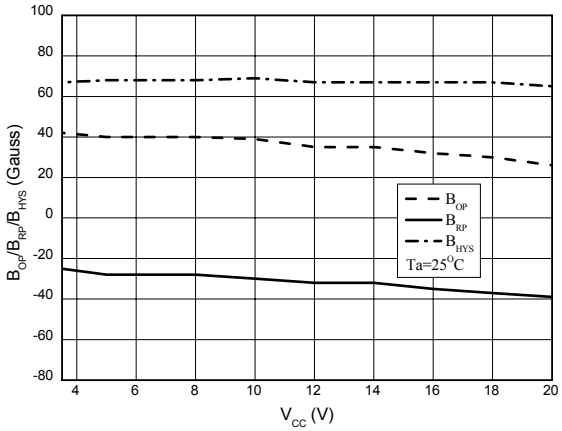


Figure 8. $B_{OP}/B_{RP}/B_{HYS}$ vs. V_{CC}

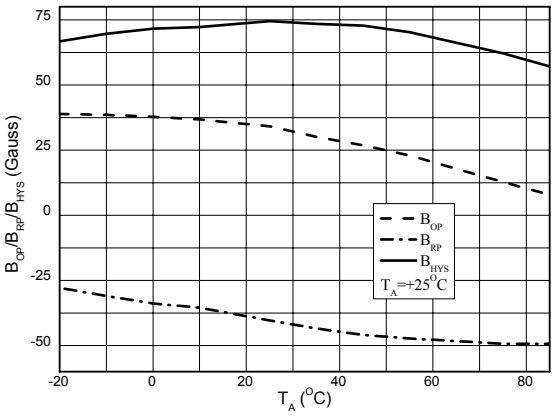


Figure 9. $B_{OP}/B_{RP}/B_{HYS}$ vs. Ambient Temperature

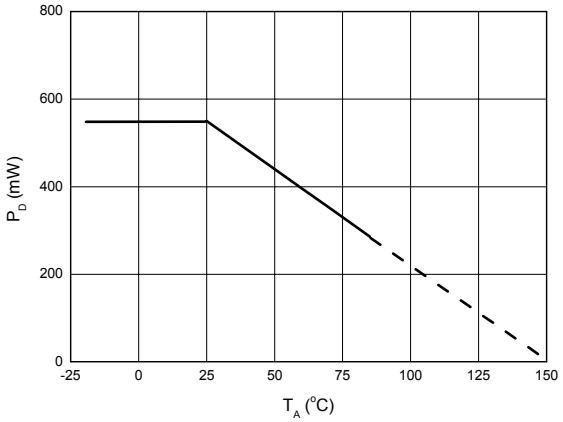


Figure 10. P_D vs. Ambient Temperature

Typical Performance Characteristics (Continued)

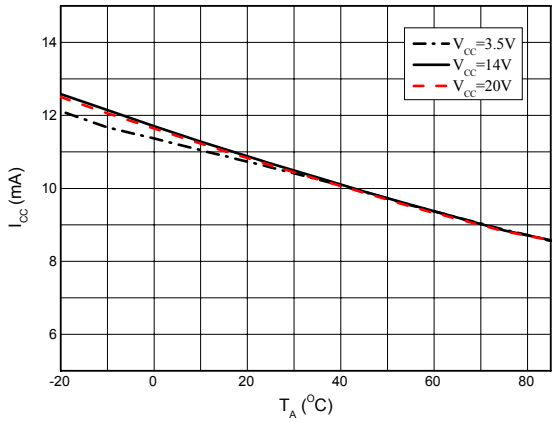


Figure 11. I_{CC} vs. Ambient Temperature

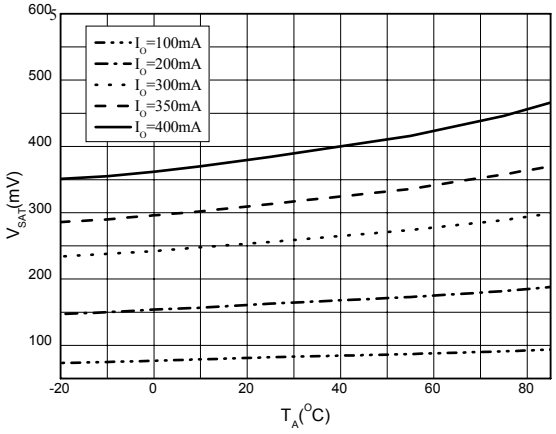


Figure 12. V_{SAT} vs. Ambient Temperature

Typical Applications

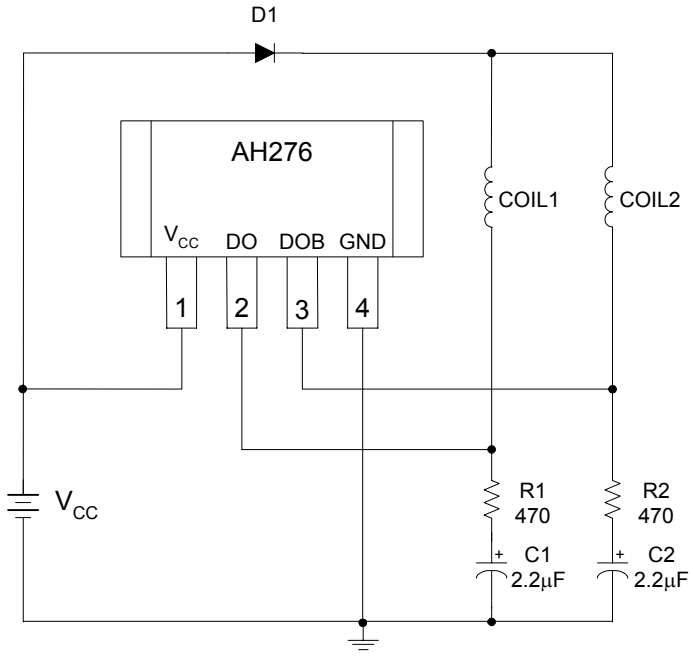
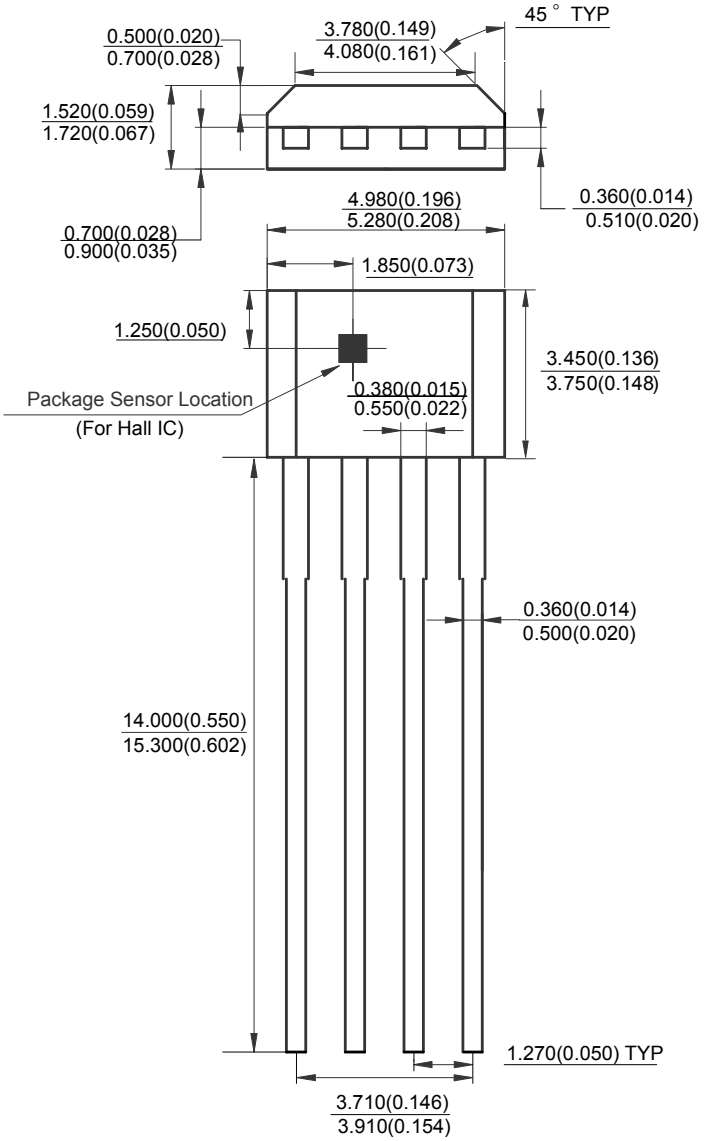


Figure 12. Typical Application Circuit

Mechanical Dimensions

TO-94 **Unit: mm(inch)**



BCD Semiconductor Manufacturing Limited

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